# 1. General description

PNP high-voltage low  $V_{CEsat}$  transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability  $\rm I_{C}$  and  $\rm I_{CM}$
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- Medium power SMD plastic package

# 3. Applications

- Electronic ballasts
- LED driver for LED chain module
- LCD backlighting
- · Flyback converters
- · Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

## 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V	-	-	-500	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-500	V
I <sub>C</sub>	collector current		-	-	-0.25	Α
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; $I_{C}$ = -50 mA; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	80	160	300	



## 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		В
3	E	emitter		P
4	С	collector	1 2 3	Ė
			SC-73 (SOT223)	sym028

# 6. Ordering information

## **Table 3. Ordering information**

Type number			
	Name	Description	Version
PBHV9050Z	SC-73	plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	SOT223

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PBHV9050Z	V9050Z

### 500 V, 250 mA PNP high-voltage low VCEsat transistor

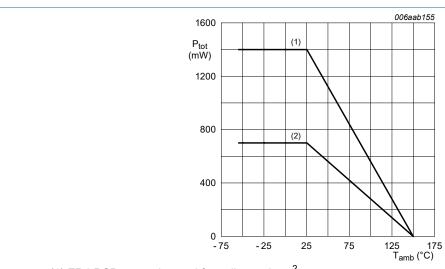
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-500	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-500	V
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V		-	-500	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-0.25	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-0.5	Α
I <sub>BM</sub>	peak base current			-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	700	mW
			[2]	-	1400	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



- (1) FR4 PCB, mounting pad for collector 6 cm<sup>2</sup>
- (2) FR4 PCB, standard footprint

Fig. 1. Power derating curves

#### 500 V, 250 mA PNP high-voltage low VCEsat transistor

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	175	K/W
junction to ambier	junction to ambient		[2]	-	-	90	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

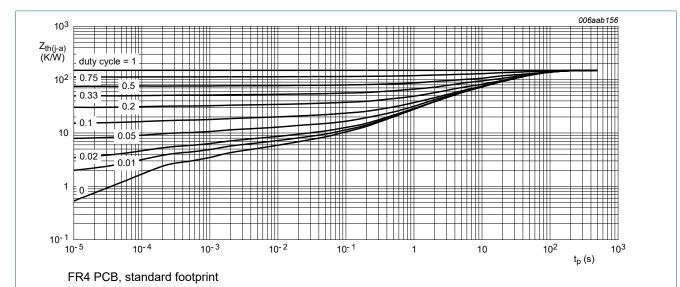


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

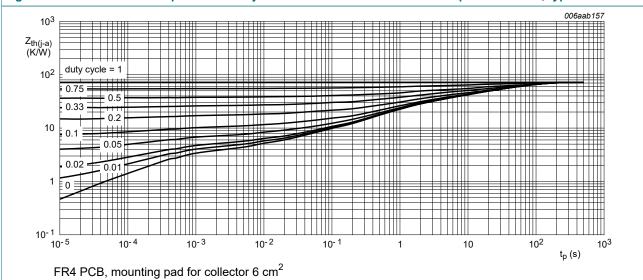


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

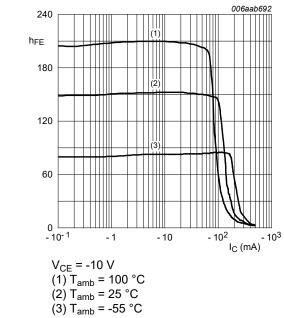
## 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 10. Characteristics

## **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -360 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -360 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-10	μA
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -360 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; $I_{C}$ = -10 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	100	160	300	
		$V_{CE}$ = -10 V; $I_{C}$ = -50 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	80	160	300	
		$V_{CE}$ = -10 V; $I_{C}$ = -100 mA; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	70	150	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -20 mA; $I_B$ = -2 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-115	-200	mV
		$I_C$ = -50 mA; $I_B$ = -10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-95	-200	mV
		$I_C$ = -100 mA; $I_B$ = -20 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; $T_{amb}$ = 25 °C	-	-140	-350	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -50 mA; $I_B$ = -10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-0.75	-0.9	V
t <sub>d</sub>	delay time	$V_{CC} = -20 \text{ V}; I_C = -0.05 \text{ A}; I_{Bon} = -5 \text{ mA};$	-	75	-	ns
t <sub>r</sub>	rise time	I <sub>Boff</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	1600	-	ns
t <sub>on</sub>	turn-on time		-	1675	-	ns
t <sub>s</sub>	storage time		-	1200	-	ns
t <sub>f</sub>	fall time		-	550	-	ns
t <sub>off</sub>	turn-off time		-	1750	-	ns
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	-	50	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	6	-	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -0.5 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	170	-	pF

#### 500 V, 250 mA PNP high-voltage low VCEsat transistor



$$(2) T_{amb} - 25 C$$

Fig. 4. DC current gain as a function of collector current; typical values

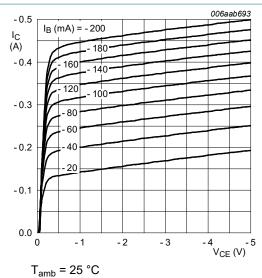
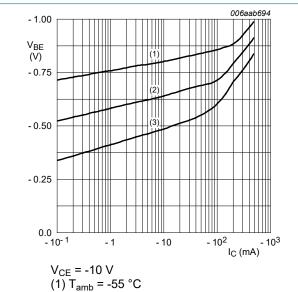


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

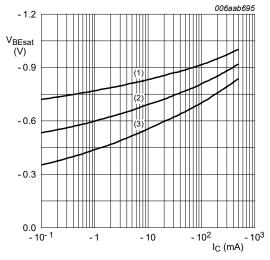


(2) T<sub>amb</sub> = 25 °C

$$(2) I_{amb} = 25 C$$

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 6. Base-emitter voltage as a function of collector current; typical values



 $I_C/I_B = 5$ 

(1)  $T_{amb} = -55$  °C

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values

#### 500 V, 250 mA PNP high-voltage low VCEsat transistor

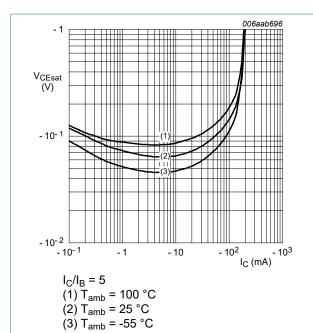


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

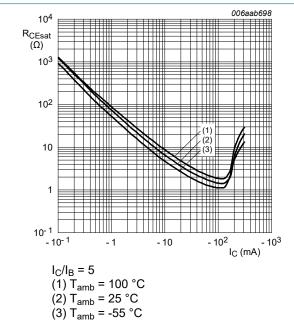


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

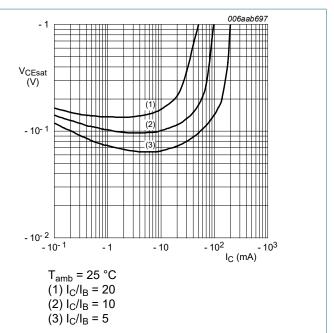


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

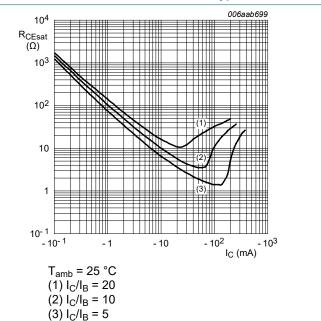
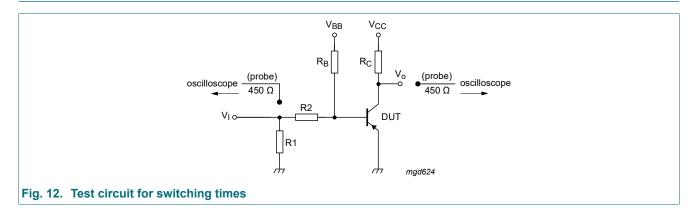


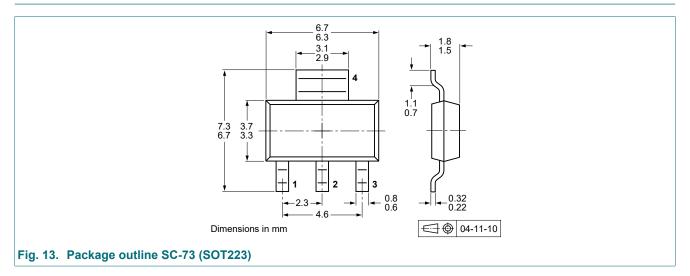
Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

## 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 11. Test information

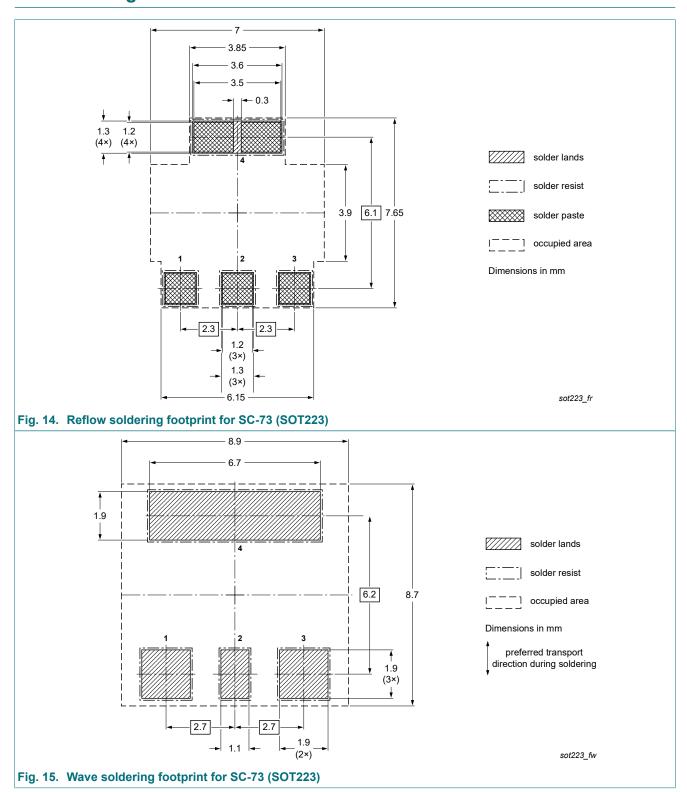


# 12. Package outline



## 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 13. Soldering



# 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 14. Revision history

#### **Table 8. Revision history**

able of Reviews							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBHV9050Z v.3	20241009	Product data sheet	-	PBHV9050Z v.2			
Modifications:	Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).						
PBHV9050Z v.2	20230717	Product data sheet	-	PBHV9050Z v.1			
PBHV9050Z v.1	20100819	Product data sheet	-	-			

### 500 V, 250 mA PNP high-voltage low VCEsat transistor

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PBHV9050Z

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